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# Product Brief PE64904 

## For full datasheet, please visit dtc.psemi.com.

## Product Description

The PE64904 is a DuNE ${ }^{\text {TM }}$-enhanced Digitally Tunable Capacitor (DTC) based on Peregrine's UltraCMOS ${ }^{\circledR}$ technology. DTC products provide a monolithically integrated impedance tuning solution for demanding RF applications.

The PE64904 offers high RF power handling and ruggedness, while meeting challenging harmonic and linearity requirements.

This highly versatile product can be used in series or shunt configurations to support a wide variety of tuning circuit topologies.

The device is controlled through the widely supported 3-wire (SPI compatible) interface. All decoding and biasing is integrated on-chip and no external bypassing or filtering components are required.

Peregrine's DuNE ${ }^{T M}$ technology enables excellent linearity and exceptional harmonic performance. DuNE devices deliver performance superior to GaAs devices with the economy and integration of conventional CMOS.

Figure 1. Functional Block Diagram


# UltraCMOS ${ }^{\oplus}$ Digitally Tunable Capacitor (DTC) 100-3000 MHz 

## Features

- 3-wire (SPI compatible) Serial Interface with built-in bias voltage generation and ESD protection
- DuNE ${ }^{\text {TM }}$-enhanced UltraCMOS ${ }^{\circledR}$ device
- 5-bit 32-state Digitally Tunable Capacitor
- Series configuration C = 0.60-4.60 pF (7.7:1 tuning ratio) in discrete 129 fF steps
- Shunt configuration $\mathrm{C}=1.14-5.10 \mathrm{pF}$ (4.6:1 tuning ratio) in discrete 129 fF steps
- High RF Power Handling (up to 38 dBm, 30 Vpk RF) and High Linearity
- Wide power supply range (2.3 to 3.6 V ) and low current consumption (typ. $140 \mu \mathrm{~A}$ at 2.6 V )
- Excellent 1.5 kV HBM ESD tolerance on all pins
- $2 \times 2 \times 0.45 \mathrm{~mm}$ QFN package
- Applications include:
- Tunable Filter Networks
- Tunable Antennas
- RFID
- Tunable Matching Networks
- Phase Shifters
- Wireless Communications

Figure 2. Package Type
10L $2 \times 2 \times 0.45 \mathrm{~mm}$ QFN package


Table 1. Electrical Specifications @ $25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=2.6 \mathrm{~V}$

| Parameter | Configuration | Condition | Min | Typ | Max | Unit |
| :--- | :---: | :--- | :---: | :---: | :---: | :---: |
| Operating Frequency Range | Both |  | 100 |  | 3000 | MHz |
| Minimum Capacitance | Series | State $=00000,100 \mathrm{MHz}(\mathrm{RF}+$ to RF-) |  |  |  |  |
| State $=00000,100 \mathrm{MHz}(R F+$ to Grounded RF-) |  |  |  |  |  |  |$)$

Figure 3. Pin Configuration (Top View)


Table 2. Pin Descriptions

| Pin \# | Pin Name | Description |
| :---: | :---: | :--- |
| 1 | RF- | Negative RF Port ${ }^{1}$ |
| 2 | RF- | Negative RF Port ${ }^{1}$ |
| 3 | DGND | Ground |
| 4 | VDD | Power supply pin |
| 5 | SCL | Serial interface Clock input |
| 6 | SEN | Serial Interface Latch Enable Input |
| 7 | SDA | Serial interface Data input |
| 8 | RF+ | Positive RF Port ${ }^{1}$ |
| 9 | RF+ | Positive RF Port ${ }^{1}$ |
| 10 | GND | RF Ground |

Note: 1. Pins 1-2 and 8-9 must be tied together on PCB for optimal performance

## Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS ${ }^{\circledR}$
devices are immune to latch-up.

## Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE64904 in the 10 -lead $2 \times 2 \times 0.45 \mathrm{~mm}$ QFN package is MSL1.

Table 3. Operating Ranges

| Parameter | Min | Typ | Max | Units |
| :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{DD}}$ Supply Voltage | 2.3 | 2.6 | 3.6 | V |
| $\mathrm{I}_{\mathrm{DD}}$ Power Supply Current |  | 140 | 200 | $\mu \mathrm{~A}$ |
| $\left(\mathrm{~V}_{\mathrm{DD}}=2.6 \mathrm{~V}\right)$ | 1.2 | 1.8 | 3.6 | V |
| $\mathrm{~V}_{\mathrm{IH}}$ Control Voltage High | 0 | 0 | 0.57 | V |
| $\mathrm{~V}_{\mathrm{IL}}$ Control Voltage Low |  |  |  |  |
| Peak Operating RF Voltage @100 MHz ${ }^{1}$ |  | 30 | Vpk |  |
| RF+ to RF- |  |  | 30 | Vpk |
| RF+ and/or RF- to Ground | -40 |  | +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {OP }}$ Operating Temperature Range | -65 |  | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {ST }}$ Storage Temperature Range |  |  |  |  |

Note: 1. De-rated over frequency
Table 4. Absolute Maximum Ratings

| Symbol | Parameter/Conditions | Min | Max | Units |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{DD}}$ | Power supply voltage | -0.3 | 4.0 | V |
| $\mathrm{~V}_{1}$ | Voltage on any DC input | -0.3 | 4.0 | V |
| $\mathrm{~V}_{\text {ESD }}$ | ESD Voltage (HBM, MIL_STD <br> 883 Method 3015.7) |  | 1500 | V |

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Electrostatic Discharge (ESD) Precautions When handling this UltraCMOS ${ }^{\circledR}$ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

Figure 4. Package Drawing
$10 \mathrm{~L} 2 \times 2 \times 0.45 \mathrm{~mm}$


TIP VIEW

|  |  | ETSLP |
| :--- | :--- | :--- |
| $\wedge$ | MAX. | 0.500 |
|  | NUM. | 0.450 |
|  | MIN. | 0.400 |



BOTTロM VIEW


SIDE VIEW
$19-2002$

Figure 5. Marking Specifications


17-0112

| Marking Spec <br> Symbol | Package <br> Marking | Definition |
| :---: | :---: | :--- |
| PP | CG | Part number marking for PE64904 |
| ZZ | $00-99$ | Last two digits of lot code |
| $\mathbf{Y}$ | $0-9$ | Last digit of year, starting from 2009 <br> (0 for 2010, 1 for 2011, etc) |
| WW | $01-53$ | Work week |

Figure 24. Tape and Reel Specifications

## 10 -lead $2 \times 2 \times 0.45 \mathrm{~mm}$


SECTION Y-Y

| $A_{0}$ | $2.20+/-0.1$ |
| :---: | :--- | :--- |
| $B 0$ | $2.20+/-0.1$ |
| $K 0$ | $0.75+/-0.1$ |
| $F$ | $3.50+/-0.05$ |
| $P_{1}$ | $4.00+/-0.1$ |
| W | $8.00+/-0.3$ |

Table 9. Ordering Information

| Order Code | Package | Description | Shipping Method |
| :---: | :---: | :---: | :---: |
| PE64904MLBB-Z | 10-lead QFN $2 \times 2 \times 0.45 \mathrm{~mm}$ | Package Part in Tape and Reel | $3000 \mathrm{units} / T \& R$ |
| EK64904-12 | Evaluation Kit | Evaluation Kit | 1 Set/Box |

## Sales Contact and Information

For sales and contact information please visit www.psemi.com.

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